

Click here to ask an associate for production status of specific part numbers.

MAX6078A/MAX6078B

Low-Power, Low-Drift, Low-Noise Voltage Reference

General Description

The MAX6078 precision voltage reference family provides low drift and low noise at a maximum power supply current of only 15 μ A. Low-frequency noise is less than 12 μ Vp-P (2.5V output voltage option) and the temperature coefficient of the output voltage is less than 10ppm/°C.

The reference output can sink and source up to 3mA of load current and the top grade provides an initial accuracy of 0.04%. The low-drift and low-noise specifications enable enhanced system accuracy, making these devices ideal for high-precision industrial applications. A noise reduction (NR) input pin allows connection of an external capacitor to reduce wideband noise. Available output voltages include 1.25V, 2.048V, 2.5V, 3.0V, 3.3V, 4.096V, and 5.0V.

The tiny, 6-bump WLP and small, 8-pin TDFN-EP packages are suitable for systems where circuit board area is limited. The operating input voltage can range from 2.3V to 5.5V. Operation is specified over the extended industrial temperature range of -55°C to +125°C.

Applications

- High-Accuracy Industrial and Process Control
- Precision Instrumentation
- High-Resolution ADCs and DACs
- Portable and Handheld Systems

Benefits and Features

- ±0.04% Initial Accuracy
- 10ppm/°C (max) Temperature Drift
- 12µV_{P-P} Noise (0.1Hz to 10Hz) at 2.5V
- 15µA Supply Current
- Long-Term Drift: 16ppm (typ, 4000hrs)
- 3mA Source/Sink Load Current
- Filter Option Reduces High-Frequency Noise
- 100mV Dropout Voltage
- 1.5mm x 1.3mm (0.5mm pitch), 6-Bump WLP and 2mm x 3mm, 8-Pin TDFN-EP Packages
- Voltage Output Options: 1.25V, 2.048V, 2.5V, 3.0V, 3.3V, 4.096V, and 5.0V

Simplified Block Diagram

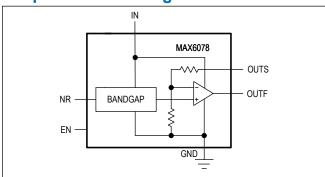


TABLE OF CONTENTS

General Description	. 1
Applications	. 1
Benefits and Features	. 1
Simplified Block Diagram	. 1
Absolute Maximum Ratings	. 4
Package Information	. 4
8 TDFN	. 4
8 WLP	. 4
Electrical Characteristics – 2.5V	. 4
Electrical Characteristics – 3.0V	. 6
Electrical Characteristics – 3.3V	. 7
Electrical Characteristics – 5.0V	. 8
Typical Operating Characteristics	10
Pin Configurations	13
6 WLP	13
8 TDFN-EP	13
Pin Description	13
Typical Operating Circuit	14
Detailed Description	15
Wideband Noise Reduction (NR)	15
Output Bypassing	15
Turn-On Time	15
Output Force and Sense	15
Shutdown	15
Thermal Hysteresis	15
Applications Information	16
Precision Current Source	16
Ordering Information	17
Davisian History	40

MAX6078A/MAX6078B

Low-Power, Low-Drift, Low-Noise Voltage Reference

LIST OF FIGURES	
Figure 1. Noise Reduction Capacitor	. 15
Figure 2. Precision Current Source	. 16

Low-Power, Low-Drift, Low-Noise Voltage Reference

Absolute Maximum Ratings

OUTF to GND	0.3V to (V _{IN} + 0.3)V	Maximum Continuous Power Dissipation $(T_A = +70^{\circ}C)$.
OUTS to GND	0.3V to +6V	TDFN (derate 16.7mW/°C above +70°C)1333.3mW
IN to GND	0.3V to +6V	WLP (derate 12.34mW/°C above +70°C)987.2mW
EN to GND	0.3V to +6V	Operating Temperature Range55°C to +125°C
NR to GND	0.3V to (V _{IN} + 0.3)V	Storage Temperature Range65°C to +150°C
Current to/from OUTF	50mA	Lead Temperature (soldering, 10s)+300°C
Current to/from OUTS/NR/EN	20mA	Soldering Temperature (reflow)+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

8 TDFN

Package Code	T823+1C
Outline Number	21-0174
Land Pattern Number	90-0091
Thermal Resistance, Four-Layer Board	
Junction to Ambient (θ _{JA})	60°C/W
Junction to Case (θ_{JC})	11°C/W

8 WLP

Package Code	W61L1+1
Outline Number	<u>21-100365</u>
Land Pattern Number	Refer to Application Note 1891
Thermal Resistance, Four-Layer Board	
Junction to Ambient (θ _{JA})	81.03°C/W
Junction to Case (θ _{JC})	N/A

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics – 2.5V

 $(V_{IN} = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F, T_A = -55^{\circ}C$ to +125°C, unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage Accuracy		T _A = +25°C	-0.04		+0.04	%
Output Voltage Temperature Drift TCV _{OU}	TCV	-40°C to +125°C (<u>Note 2</u>)		2	10	nnm/°C
	ICVOUT	-55°C to +125°C (<u>Note 2</u>)		2	10	ppm/°C
Line Regulation		Over specified operating input voltage range		10	175	μV/V

Electrical Characteristics – 2.5V (continued)

 $(V_{IN}$ = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F, T_A = -55 $^{\circ}$ C to +125 $^{\circ}$ C, unless otherwise specified. Typical values are at T_A = +25 $^{\circ}$ C (*Note* 1))

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Load Regulation		-3mA ≤ I _{OUT} ≤ +3m	nA		5	125	μV/mA
Oronout Voltago		I _{OUT} = 3mA (<u>Note</u>	<u>3</u>)			100	m\/
Dropout Voltage		I _{OUT} = 100μA (<u>Not</u>	<u>e 3</u>)			10	mV
Output Current	lout	Guaranteed by load	d regulation	-3		+3	mA
Short-Circuit Current	laa	Sourcing to ground			36		mA
Short-Circuit Current	I _{SC}	Sinking current from	Sinking current from V _{IN}		24		IIIA
			0 to 4000hrs		16		
			0 to 1000hrs		9.8		
Long-Term Stability		T _A = +35°C	1000hrs to 2000hrs		2.5		ppm
			2000hrs to 3000hrs		1.89		
			3000hrs to 4000hrs		1.96		
Thermal Hysteresis		(<u>Note 4</u>)			20		ppm
		0.1Hz to 10Hz, C _O	_{UT} = 0.1μF		12		μV _{P-P}
Output Noise Voltage	e _{OUT}	10Hz to 10kHz, C _O	_{UT} = 0.1μF		30		
Catput Noise Voltage	9001	10Hz to 10kHz, C _O 0.01μF	_{UT} = 0.1μF, C _{NR} =		20		μV _{RMS}
Output Noise Spectral		f = 100Hz, C _{OUT} = 0.1µF			580		->///
Density		f = 100Hz, C _{OUT} = 0.1μF, C _{NR} = 0.01μF			385		nV/√Hz
Ripple Rejection		f = 60Hz			50		dB
		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		50		- ms
Turn-On Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		5		
5 11 0 W T		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		
Enable Settling Time	t _{EN}	Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		3		- ms
Capacitive-Load Stability Range				0.1		4.7	μF
Supply Voltage	V _{IN}			2.7		5.5	V
			T _A = +25°C		10	15	
		V _{IN} = 5V	T _A = -55°C to +85°C			16.5	- - - -
Quiescent Supply	,		T _A = -55°C to +125°C			18	
Current	I _{IN}		T _A = +25°C		9	14	
		$V_{IN} = 3.3V$ $T_A = -55^{\circ}0$ $+85^{\circ}C$	$T_A = -55^{\circ}C$ to			15.5	
			T _A = -55°C to +125°C			17	
Shutdown Supply Current	I _{SD}				0.1	2	μА

Electrical Characteristics – 2.5V (continued)

 $(V_{IN}$ = +3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F, T_A = -55°C to +125°C, unless otherwise specified. Typical values are at T_A = +25°C (*Note* 1))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Enable Input Current	I _{EN}				0.1	μA
Enable Logic-High	V _{IH}		0.7 x V _{IN}			V
Enable Logic-Low	V _{IL}				0.3 x V _{IN}	V

Electrical Characteristics – 3.0V

 $(V_{IN} = +5V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F, T_A = -55^{\circ}C$ to $+125^{\circ}C$, unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	CONI	DITIONS	MIN	TYP	MAX	UNITS	
Output Voltage Accuracy		T _A = +25°C	T _A = +25°C			+0.04	%	
Output Voltage	TO) /	-40°C to +125°C (N	lote 2)		2	10	/90	
Temperature Drift	TCV _{OUT}	-55°C to +125°C (<u>N</u>	lote 2)		2	10	ppm/°C	
Line Regulation		Over specified oper range	rating input voltage		10	175	μV/V	
Load Regulation		-3mA ≤ I _{OUT} ≤ +3m	A		5	125	μV/mA	
Dronout Voltogo		I _{OUT} = 3mA (<u>Note</u> 3	<u>3</u>)			100	m)/	
Dropout Voltage		I _{OUT} = 100μA (<u>Note</u>	<u>9 3</u>)			10	mV	
Output Current	I _{OUT}	Guaranteed by load	l regulation	-3		+3	mA	
Short Circuit Current	l	Sourcing to ground			36		m A	
Short-Circuit Current	I _{SC}	Sinking current from	ı V _{IN}		24		- mA	
			0 to 4000hrs		16			
		T _A = +35°C	0 to 1000hrs		9.8		ppm	
Long-Term Stability			1000hrs to 2000hrs		2.5			
			2000hrs to 3000hrs		1.89			
			3000hrs to 4000hrs		1.96		1	
Thermal Hysteresis		(<u>Note 4</u>)	'		20		ppm	
		0.1Hz to 10Hz, C _{Ol}	_{JT} = 0.1µF		12		µV _{P-P}	
Output Noise Voltage	e _{OUT}	10Hz to 10kHz, C _{OUT} = 0.1μF			30			
Output Noise Voltage	5001	10Hz to 10kHz, C _{OUT} = 0.1µF, C _{NR} = 0.01µF			20		μV _{RMS}	
Output Noise Spectral		f = 100Hz, C _{OUT} =	0.1µF		580		nV/√Hz	
Density		f = 100Hz, C _{OUT} =	f = 100Hz, C _{OUT} = 0.1µF, C _{NR} = 0.01µF				110/7002	
Ripple Rejection		f = 60Hz			50		dB	
Turn On Calling Time		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		50			
Turn-On Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		5		ms	
	4	Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		ma	
Enable Settling Time	t _{EN}	Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		3		ms	

Analog Devices | 6 www.analog.com

Electrical Characteristics – 3.0V (continued)

 $(V_{IN} = +5V, I_{OUT} = 0mA, C_{OUT} = 0.1 \mu F, T_A = -55 ^{\circ}C$ to $+125 ^{\circ}C$, unless otherwise specified. Typical values are at $T_A = +25 ^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Capacitive-Load Stability Range			0.1		4.7	μF
Supply Voltage	V _{IN}		3.2		5.5	V
Quiescent Supply Current		T _A = +25°C		10	15	
	I _{IN}	T _A = -55°C to +85°C			16.5	μΑ
Current		T _A = -55°C to +125°C			18	1
Shutdown Supply Current	I _{SD}			0.1	2	μA
Enable Input Current	I _{EN}				0.1	μA
Enable Logic-High	V _{IH}		0.7 x V _{IN}			V
Enable Logic-Low	V _{IL}				0.3 x V _{IN}	V

Electrical Characteristics – 3.3V

 $(V_{IN} = +5V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F, T_A = -55^{\circ}C$ to $+125^{\circ}C$, unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	cc	ONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage Accuracy		T _A = +25°C	-0.04		+0.04	%	
Output Voltage	TC\/	-40°C to +125°C	-40°C to +125°C (<i>Note 2</i>)			10	nnm/°C
Temperature Drift	TCV _{OUT}	-55°C to +125°C	(<u>Note 2</u>)		2	10	ppm/°C
Line Regulation		Over specified or range	perating input voltage		10	175	μV/V
Load Regulation		-3mA ≤ I _{OUT} ≤ +	3mA		5	125	μV/mA
Dronout Voltage		I _{OUT} = 3mA (<u>Not</u>	<u>fe 3</u>)			100	- mV
Dropout Voltage		I _{OUT} = 100μA (Λ	<u>lote 3</u>)			10] ""
Output Current	lout	Guaranteed by lo	oad regulation	-3		+3	mA
01 10: "0		Sourcing to ground			36		mΛ
Short-Circuit Current	I _{SC}	Sinking current from V _{IN}			24		- mA
			0 to 4000hrs		16		
			0 to 1000hrs		9.8		
Long-Term Stability		T _A = +35°C	1000hrs to 2000hrs		2.5		ppm
			2000hrs to 3000hrs		1.89]
				3000hrs to 4000hrs		1.96	
Thermal Hysteresis		(<u>Note 4</u>)			20		ppm
		0.1Hz to 10Hz, C	C _{OUT} = 0.1µF		12		µV _{P-P}
Output Noise Voltage	BOUT.	10Hz to 10kHz, 0	C _{OUT} = 0.1µF		30		
Output Noise Voltage	6001	e _{OUT} 10Hz to 10kHz, C _{OUT} = 0.1μF, C _{NR} = 0.01μF			20		μV _{RMS}
Output Noise Spectral		f = 100Hz, C _{OUT}	= 0.1µF		580		nV/√Hz
Density		f = 100Hz, C _{OUT}	= 0.1µF, C _{NR} = 0.01µF		385		
Ripple Rejection		f = 60Hz			50		dB

Electrical Characteristics – 3.3V (continued)

 $(V_{IN} = +5V, I_{OUT} = 0mA, C_{OUT} = 0.1 \mu F, T_A = -55 ^{\circ}C$ to $+125 ^{\circ}C$, unless otherwise specified. Typical values are at $T_A = +25 ^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
Turn-On Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		50		ms
		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		5		1115
Enable Settling Time	t	Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		ms
		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		3		1115
Capacitive-Load Stability Range				0.1		4.7	μF
Supply Voltage	V _{IN}			3.5		5.5	V
		T _A = +25°C			10	15	
Quiescent Supply Current	I _{IN}	T _A = -40°C to +125°C				16.5	μΑ
Current		T _A = -55°C to +125°C				18	
Shutdown Supply Current	I _{SD}				0.1	2	μΑ
Enable Input Current	I _{EN}					0.1	μΑ
Enable Logic-High	V _{IH}			0.7 x V _{IN}			V
Enable Logic-Low	V _{IL}					0.3 x V _{IN}	V

Electrical Characteristics – 5.0V

 $(V_{IN}$ = +5.5V, I_{OUT} = 0mA, C_{OUT} = 0.1 μ F, T_A = -55°C to +125°C, unless otherwise specified. Typical values are at T_A = +25°C (*Note* 1))

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Output Voltage Accuracy		T _A = +25°C		-0.04		+0.04	%	
Output Voltage	TC)/	-40°C to +125°C (<u>Note 2</u>)			1	10	nnm/°C	
Temperature Drift	TCV _{OUT}	-55°C to +125°C (<u>Note 2</u>)			2	10	ppm/°C	
Line Regulation		Over specified operating input voltage range			15	700	μV/V	
Load Regulation		-3mA ≤ I _{OUT} ≤ +3	-3mA ≤ I _{OUT} ≤ +3mA		5	125	μV/mA	
Dranaut Valtaga	I _{OUT} = 3mA (<i>Note 3</i>)			40	100	\		
Dropout Voltage		I _{OUT} = 100μA (<i>Note 3</i>)			1.5	10	- mV	
Output Current	lout	Guaranteed by load regulation		-3		+3	mA	
Short-Circuit Current	laa	Sourcing to ground			36		mA	
Short-Circuit Current	I _{SC}	Sinking current from V _{IN}			24		l IIIA	
			0 to 4000hrs		16			
Long-Term Stability		T _A = +35°C	0 to 1000hrs		9.8			
			1000hrs to 2000hrs		2.5		ppm	
			2000hrs to 3000hrs		1.89			
			3000hrs to 4000hrs		1.96			
Thermal Hysteresis		(<u>Note 4</u>)			20		ppm	

Electrical Characteristics – 5.0V (continued)

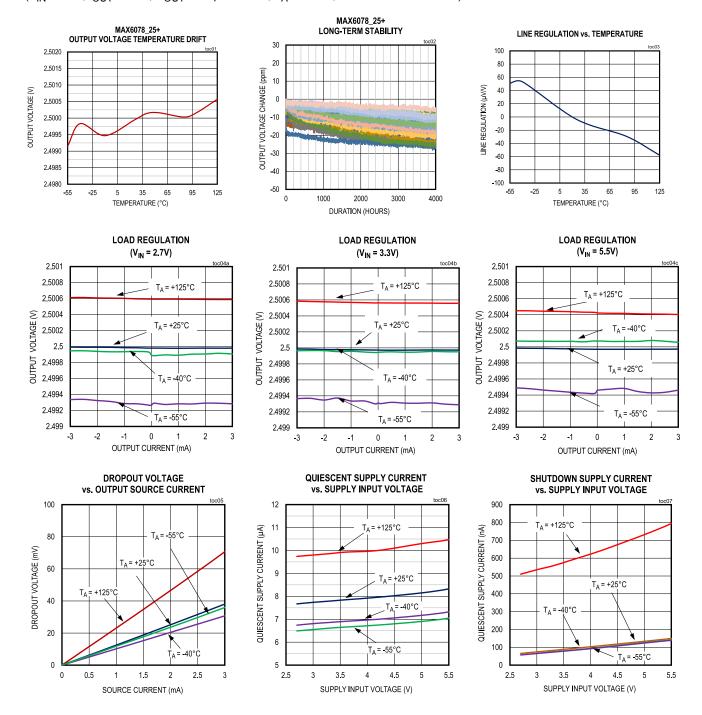
 $(V_{IN} = +5.5V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F, T_A = -55^{\circ}C$ to +125°C, unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$ (Note 1)

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS	
Output Noise Voltage	e _{OUT}	0.1Hz to 10Hz, $C_{OUT} = 0.1 \mu F$			27		μV_{P-P}	
		10Hz to 10kHz, C _{OUT} = 0.1μF			31			
		10Hz to 10kHz, C _{OUT} = 0.1μF, C _{NR} = 0.01μF		21		μV _{RMS}		
Output Noise Spectral		f = 100Hz, C _{OUT} = 0.1μF		1100		nV/√Hz		
Density		f = 100Hz, C _{OUT} = 0.1μF, C _{NR} = 0.01μF		660				
Ripple Rejection		f = 60Hz			50		dB	
		Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		50		- ms	
Turn-On Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		5			
Enable Settling Time	t _{EN}	Settling to 0.1%, C _{OUT} = 0.1µF	C _{NR} = 0.01µF		30		- ms	
Enable Settling Time		Settling to 0.1%, C _{OUT} = 0.1µF	No C _{NR}		3			
Capacitive-Load Stability Range				0.1		4.7	μF	
Supply Voltage	V _{IN}			5.2		5.5	V	
0	I _{IN}	T _A = +25°C			10	15		
Quiescent Supply Current		T _A = -55°C to +85°C				16.5	μΑ	
		T _A = -55°C to +125°C				18		
Shutdown Supply Current	I _{SD}				0.1	2	μΑ	
Enable Input Current	I _{EN}					0.1	μA	
Enable Logic-High	V _{IH}			0.7 x V _{IN}			V	
Enable Logic-Low	V _{IL}					0.3 x V _{IN}	V	

- Note 1: Limits are 100% tested at T_A = +25°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.
- **Note 2:** Temperature coefficient is calculated using the "box method" which measures temperature drift as the maximum voltage variation over a specified temperature range.
- Note 3: Dropout voltage is defined as the minimum differential voltage (V_{IN} V_{OUT}) at which V_{OUT} decreases by 0.2% from its original value. V_{IN} = 3.3V for output voltages of 1.25V, 2.048V, and 2.5V; V_{IN} = 5V for output voltages of 3V, 3.3V, 4.096V; V_{IN} = 5.5V for output voltage of 5V.
- Note 4: Thermal hysteresis is defined as the change in +25°C output voltage before and after cycling the device from T_{MAX} to T_{MIN}.

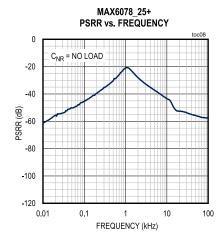
Typical Operating Characteristics

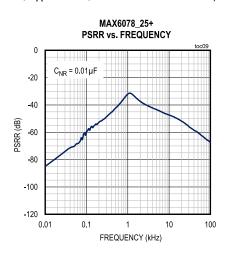
 $(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F \text{ to GND}, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

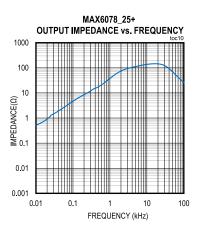


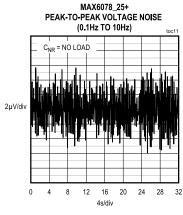
Typical Operating Characteristics (continued)

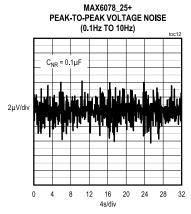
 $(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F \text{ to GND}, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

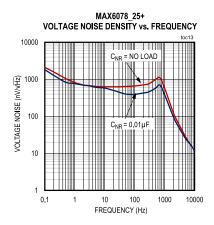


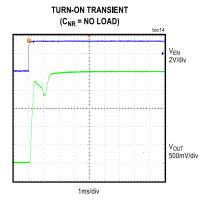


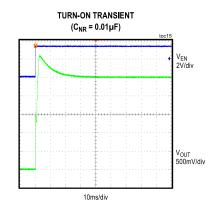


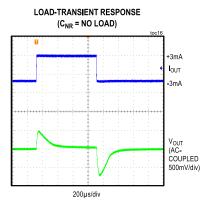






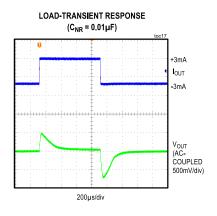


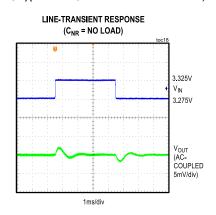


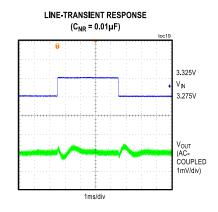


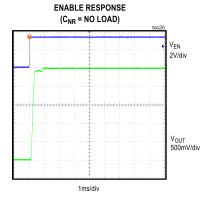
Typical Operating Characteristics (continued)

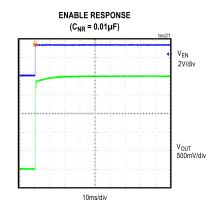
 $(V_{IN} = 3.3V, I_{OUT} = 0mA, C_{OUT} = 0.1\mu F \text{ to GND}, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

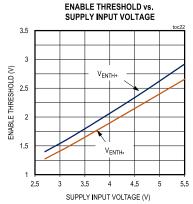


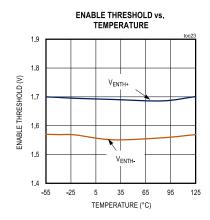






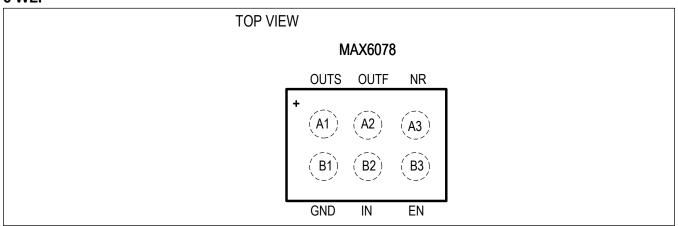




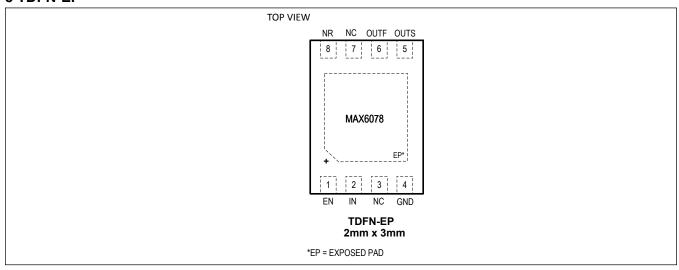


Pin Configurations

6 WLP



8 TDFN-EP



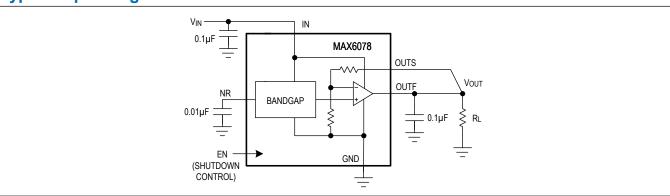
Pin Description

PIN					
6 WLP	8 TDFN-EP	NAME	FUNCTION		
A1	5	OUTS	Voltage Reference Output Sense. Connect OUTF and OUTS as close as possible to the load.		
A2	6	OUTF	Voltage Reference Force Output. Connect OUTF and OUTS as close as possible to the load. Bypass OUTF with a capacitor to GND.		
A3	8	NR	Noise Reduction Input. Connect a 0.01µF capacitor from NR to ground to provide wideband noise filtering. Leave unconnected if not used.		
B1	4	GND	Ground		
B2	2	IN	Supply Input		
В3	1	EN	Enable. Drive high to enable. Drive low to disable.		

Pin Description (continued)

PIN		NAME	FUNCTION		
6 WLP	8 TDFN-EP	NAME	FUNCTION		
_	3, 7	NC	No Connect. Not internally connected. May be connected to GND.		
_	EP	EP	Exposed Pad (EP). EP should not be connected to anything for the best performance, so it must be clear of any mechanical and electrical contact. Neither a copper nor a solder/paste mask must be placed underneath its land pattern. The absence of mechanical contact eliminates the possibility of paddle-induced stress on the die. The absence of electrical contact eliminates the possibility of any ground current redistribution.		

Typical Operating Circuit



Detailed Description

Wideband Noise Reduction (NR)

To improve wideband noise and transient power supply noise, connect a $0.01\mu\text{F}$ capacitor from NR to GND (see the <u>Typical Operating Characteristics</u>). Larger values do not appreciably improve noise reduction. A $0.01\mu\text{F}$ capacitor reduces the spectral noise density at 100Hz from $580\text{nV}/\sqrt{\text{Hz}}$ to $385\text{nV}/\sqrt{\text{Hz}}$ for the 2.5V output version. Noise at the input pin can affect output noise, but can be reduced by connecting an optional bypass capacitor between IN and GND, as shown in Figure 1.

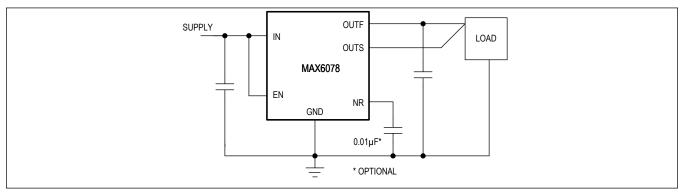


Figure 1. Noise Reduction Capacitor

Output Bypassing

Use an output capacitor with a value between $0.1\mu F$ and $4.7\mu F$. Place the output capacitor as close to OUTF as possible. For applications driving switching capacitive loads or rapidly changing load currents, use a $0.1\mu F$ capacitor in parallel with a larger load capacitor to reduce equivalent series resistance (ESR). Larger capacitor values and lower ESR reduce transients on the reference output.

Turn-On Time

These references typically turn on and settle to within 0.1% of their final value in 5ms with no capacitive loads at NR pin. A $0.1\mu F$ load capacitor at OUTF and a $0.01\mu F$ noise reduction capacitor connected to the NR input increase the turn-on time to approximately 50ms.

Output Force and Sense

These references provide independent connections for the force output (OUTF), which supplies current to the load and the feedback input that regulates the load voltage through the output sense pin (OUTS). This configuration allows for the cancellation of the voltage drop on the lines connecting the reference to the load. Connect OUTF to the load and connect OUTS to OUTF at the point where the voltage accuracy is needed (Figure 1).

Shutdown

Although the operating power supply current of these references is very low, there are some cases that require even lower supply current during shutdown conditions. Pulling EN low disables the output with an internal resistive load to ground and forces the quiescent current to less than 100nA. Pulling EN high enables normal operation. The return to normal operation occurs within the 3ms enable time delay typically.

Thermal Hysteresis

Thermal hysteresis is the change of output voltage at $T_A = +25^{\circ}\text{C}$ before and after the device is cycled over its entire operating temperature range. The typical thermal hysteresis value is 20ppm.

Applications Information

Precision Current Source

<u>Figure 2</u> shows a precision current source. The OUTF output provides the bias current for the bipolar transistor. OUTS and GND sense the voltage across the resistor and adjust the current sourced by OUTF accordingly. The voltage range of OUTF is set by the reference output voltage (OUTS) and the V_{BE} (BJT) of the output external device:

 $V_{OUTF} = V_{BE} + V_{REF}$

where:

VOUTE is the voltage on the OUTF pin,

V_{BE} is the base-emitter drop across BJT,

V_{REF} is the actual voltage reference output this part is supposed to provide.

Therefore, the input supply voltage requirement for the MAX6078 is as follows:

 $V_{IN} \ge V_{DROP}$ (dropout voltage) + V_{BE} max + V_{REF} where:

V_{DROP} is the dropout voltage of the voltage reference.

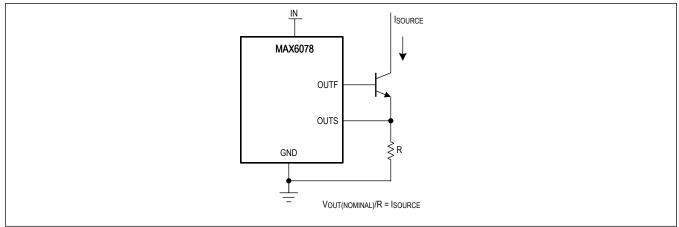


Figure 2. Precision Current Source

Ordering Information

PART NUMBER**	TEMP RANGE	PIN-PACKAGE	V _{OUT} (V)	ACCURACY (%)	TOP MARK
MAX6078BMWT12+T*	-55°C to +125°C	6 WLP	1.250	0.04	_
MAX6078AMWT21+T*	-55°C to +125°C	6 WLP	2.048	0.04	_
MAX6078AMWT25+T	-55°C to +125°C	6 WLP	2.500	0.04	+AAE
MAX6078AMWT30+T	-55°C to +125°C	6 WLP	3.000	0.04	+AAH
MAX6078AMWT33+T	-55°C to +125°C	6 WLP	3.300	0.04	+AAI
MAX6078AMWT41+T*	-55°C to +125°C	6 WLP	4.096	0.04	_
MAX6078AMWT50+T	-55°C to +125°C	6 WLP	5.000	0.04	+AAK
MAX6078BMTA12+T*	-55°C to +125°C	8 TDFN-EP	1.250	0.04	_
MAX6078AMTA21+T*	-55°C to +125°C	8 TDFN-EP	2.048	0.04	_
MAX6078AMTA25+T*	-55°C to +125°C	8 TDFN-EP	2.500	0.04	_
MAX6078AMTA30+T*	-55°C to +125°C	8 TDFN-EP	3.000	0.04	_
MAX6078AMTA33+T*	-55°C to +125°C	8 TDFN-EP	3.300	0.04	_
MAX6078AMTA41+T*	-55°C to +125°C	8 TDFN-EP	4.096	0.04	_
MAX6078AMTA50+T*	-55°C to +125°C	8 TDFN-EP	5.000	0.04	_

⁺ Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

^{*}Future product—contact factory for availability.

^{**}MAX6078B: 1.25V output, MAX6078A: all other output voltage options.

MAX6078A/MAX6078B

Low-Power, Low-Drift, Low-Noise Voltage Reference

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/19	Initial release	_
1	9/20	Updated Benefits and Features, Electrical Characteristics, Typical Operating Characteristics, and Ordering Information table	1, 4, 5, 7–9, 14
2	3/21	Updated the Electrical Characteristics and Ordering Information tables	6–8, 16
3	6/23	Updated Electrical Characteristics, Typical Operating Characteristics, Pin Configurations, Pin Description, and Ordering Information table	8-9, 11, 13-14, 17

